## NSN 5961-00-843-1009

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Inclosure Material:	
Metal	
Overall Length:	
0.260 inches	
Terminal Length:	
1.500 inches	
Overall Diameter:	
0.370 inches	
Internal Configuration:	
Junction contact	
Internal Junction Configuration	on:
Pnp	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Germanium	
Voltage Rating In Volts Per Ch	naracteristic:
25.0 breakdown voltage, colled	ctor-to-base, emitter open and 12.0 breakdown voltage, emitter-to-base, collector open
Current Rating Per Characteri	stic:
100.00 milliamperes source cuto	off current
Power Rating Per Characteris	tic:
150.0 milliwatts small-signal inp	ut power, common-collector
Maximum Operating Tempura	ture Per Measurement Point:
100.0 degrees celsius ambient a	air
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	